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ATTORNEY DOCKET NO. CONFIRMATION NO. FIRST NAMED INVENTOR APPLICATION NO. FILING DATE P 282475 10/052,347 01/23/2002 Katsuhide Manabe F00-219-USdiv3-c "· 12/03/2002 PILLSBURY WINTHROP, LLP EXAMINER P.O. BOX 10500 MULPURI, SAVITRI MCLEAN, VA 22102 ART UNIT PAPER NUMBER 2812 DATE MAILED: 12/03/2002

Please find below and/or attached an Office communication concerning this application or proceeding

RECEIVED

PILLSBURY WINTHROP LLP/VA

DEC 0 5 2002

CL 3/3/7 MT# 202475

ATTY(S) USL KMF

DUE: 3-3-03

DKT BY (1) OTW (2) US

SEP 0 1 2003 #

Applicant(s)

Applicant(s)

Examiner

Application No.

10/052,347

Art Unit

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Office Action Summative No.

Savitri Mulpuri 2812 -- The MAILING DATE of this communication appears on the cover sheet with the corresp ndence address --Period for Reply A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely. - If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication. - Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). - Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b). 1) Responsive to communication(s) filed on Sep 17, 2002 2b) X This action is non-final. 2a) This action is FINAL. 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11; 453 O.G. 213. Disposition of Claims is/are pending in the application. 4) X Claim(s) 1-52 and 119-127 4a) Of the above, claim(s) is/are withdrawn from consideration. 5) Claim(s) 6) 💢 Claim(s) 1-52 and 119-127 is/are rejected. 7) Claim(s) is/are objected to. are subject to restriction and/or election requirement. 8) Claims **Application Papers** 9) The specification is objected to by the Examiner. 10) The drawing(s) filed on is/are a) accepted or b) objected to by the Examiner. Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a). 11) The proposed drawing correction filed on is: a) approved b) disapproved by the Examiner. If approved, corrected drawings are required in reply to this Office action. 12) The oath or declaration is objected to by the Examiner. Priority under 35 U.S.C. §§ 119 and 120 13) Acknowledgement is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some* c) None of: 1. Certified copies of the priority documents have been received. 2. Certified copies of the priority documents have been received in Application No. 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). *See the attached detailed Office action for a list of the certified copies not received. 14) Acknowledgement is made of a claim for domestic priority under 35 U.S.C. § 119(e). a) The translation of the foreign language provisional application has been received. 15) ☐ Acknowledgement is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121. 4) Interview Summary (PTO-413) Paper No(s). 1) Notice of References Cited (PTO-892) 5) Notice of Informal Patent Application (PTO-152) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) "Information Disclosure Statement(s) (PTO-1449) Paper No(s).



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DETAILED ACTION

This action is in response to the applicant 's provisions of IDS and amendment to claims filed on 9/17/02

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claims 19-36, 119-121 are rejected under 35 U.S.C. 102(b) as being anticipated by Sayyah et al.

Sayyah et al discloses a method of growing GaN or AlGaN on sapphire substrate by vapor phase epitaxy MOCVD, HCVD: Sayyah further discloses growing AlN layer in addition AlGaN and GaN layers, by using silane and with TMG, TMA, and ammonia. Sayyah et al discloses flow rate of silane is 10-1200 SCCM to obtain donor concentration of 9 X 10 ¹⁸/cm ³. Since silicon is shallow donor in GaN, the claimed electron concentration is close to that of disclosed silicon concentration of Prior art in the GaN material. In the prior art the measured silicon concentration was limited by the detect ability limit of the technique used to measure the silicon concentration. Based upon the range of flow rates of silane used in the prior art, it is conceivable that a wide range of silicon concentration spanning more than three decades variation has been achieved in the prior art. Sayyah et al do not explicitly teach conductivity. However, the above dopant silicon concentration in the prior art cover the claimed ranges of conductivity.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person

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having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 37-52, 122-127 are rejected under 35 U.S.C. 103(a) as being unpatentable over Sayyah et al. Sayyah et al does teach individual epitaxial layer of AlGaN, GaN, AlN, but does not teach using one of the layers as buffer layer. It is well known that using one of the above mentioned layers as buffer layer to reduce crystal defects in the active layers used for device.

Applicant's arguments with respect to claims 19-52, 119-127 have been considered but are most in view of the new ground(s) of rejection.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to S. Mulpuri whose telephone number is 703-305-5184. The fax phone number for the organization where this application or proceeding is assigned is 70-308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is 703-308-0956.

SÁVITRI MULPURÍ